



### Complementary Enhancement Mode MOSFET - ESD Protected

Voltage

20 / -20V

Current

0.5A / -0.5A

#### **Features**

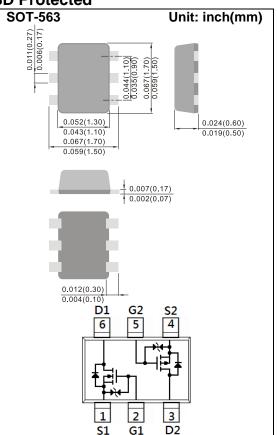
- Low Voltage Drive (1.2V)
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

#### **Mechanical Data**

• Case: SOT-563 Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.00009 ounces, 0.026 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMET	SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	20	-20	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 10	<u>+</u> 10	V
Continuous Drain Current		I <sub>D</sub>	0.5	-0.5	Α
Pulsed Drain Current (Note 4)		I <sub>DM</sub>	1.0	-1.0	Α
	T <sub>a</sub> =25°C		30	00	mW
Power Dissipation	Derate above 25°C	P <sub>D</sub>	2	mW/°C	
Operating Junction and Storage	$T_{J}$ , $T_{STG}$	-55~150		°C	
Typical Thermal Resistance - Junction to Ambient (Note 3)		$R_{\theta JA}$	417		°C/W





## N-Channel Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static					•	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> = 250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	0.3	0.64	0.9	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS} = 4.5V, I_{D} = 500mA$	-	0.31	0.4	
		$V_{GS} = 2.5V, I_{D} = 200mA$	-	0.36	0.65	
		V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 100mA	-	0.43	0.8	Ω
		V <sub>GS</sub> = 1.5V, I <sub>D</sub> = 50mA	-	0.51	1.2	
		V <sub>GS</sub> = 1.2V, I <sub>D</sub> = 20mA	-	0.71	3.0	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 16V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 8V, V <sub>DS</sub> =0V	-	<u>+</u> 0.5	<u>+</u> 10	uA
Dynamic (Note 5)						
Total Gate Charge	$Q_g$	$V_{DS}$ =10V, $I_{D}$ =500mA, $V_{GS}$ =4.5V	-	1.4	-	nC
Gate-Source Charge	$Q_gs$		-	0.22	-	
Gate-Drain Charge	$Q_{gd}$		-	0.21	-	
Input Capacitance	Ciss	10/ 10/ 1/ 01/	-	67	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,	-	19	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	6	-	
Turn-On Delay Time	td <sub>(on)</sub>	101/11/12	_	2.8	-	ns
Turn-On Rise Time	tr	$V_{DD}$ =10V, $I_{D}$ =150mA, $V_{GS}$ =4V, $V_{GS}$ =4V,	_	20	-	
Turn-Off Delay Time	td <sub>(off)</sub>		_	23	-	
Turn-Off Fall Time	tf	$R_G=10\Omega$ (Note 1,2)	-	23	-	
Drain-Source Diode						
Maximum Continuous Drain-Source				-	500	mA
Diode Forward Current	I <sub>S</sub>		-			
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = 500mA, V <sub>GS</sub> =0V	-	0.87	1.3	V





### P-Channel Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-0.3	-0.6	-1.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-500mA	-	0.9	1.2	Ω
		V <sub>GS</sub> =-2.5V,I <sub>D</sub> =-200mA	ı	1.07	1.5	
		V <sub>GS</sub> =-1.8V,I <sub>D</sub> =-100mA	-	1.25	2.2	
		V <sub>GS</sub> =-1.5V,I <sub>D</sub> =-40mA	-	1.42	3.6	
		V <sub>GS</sub> =-1.2V,I <sub>D</sub> =-10mA	-	1.7	6.0	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-16V,V <sub>GS</sub> =0V	ı	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 8V,V <sub>DS</sub> =0V	-	<u>+</u> 2	<u>+</u> 10	uA
Dynamic (Note 5)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-10V, I <sub>D</sub> =-500mA, V <sub>GS</sub> =-4.5V	-	1.4	-	nC
Gate-Source Charge	$Q_gs$		-	0.19	-	
Gate-Drain Charge	$Q_{gd}$		-	0.2	-	
Input Capacitance	Ciss	101/11/101/	-	38	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V,	-	15	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	9	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	7.2	-	ns
Turn-On Rise Time	tr	$V_{DD}$ =-10V, $I_{D}$ =-500mA,	-	21	-	
Turn-Off Delay Time	td <sub>(off)</sub>	V <sub>GS</sub> =-4.5V,	-	85	-	
Turn-Off Fall Time	tf	$R_G=6\Omega$ (Note 1,2)	-	116	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I <sub>S</sub>		-	_	-500	mA
Diode Forward Current	.5					
Diode Forward Voltage	$V_{SD}$	$I_S$ =-500mA, $V_{GS}$ =0V	-	-0.9	-1.3	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. ROJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





#### **N-Channel TYPICAL CHARACTERISTIC CURVES**

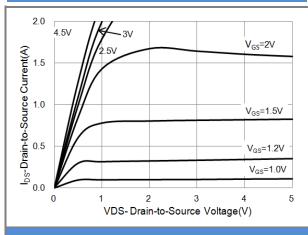


Fig.1 On-Region Characteristics

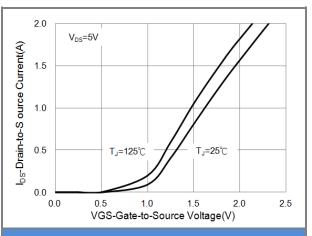


Fig.2 Transfer Characteristics

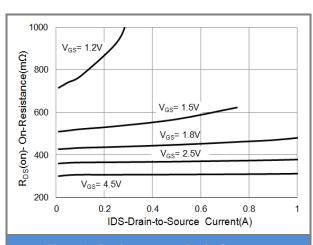


Fig.3 On-Resistance vs. Drain Current

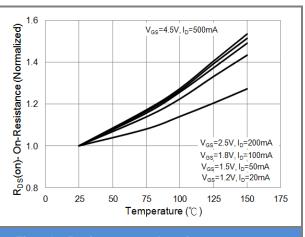
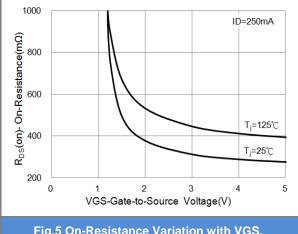
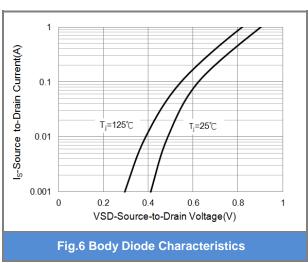


Fig.4 On-Resistance vs. Junction temperature



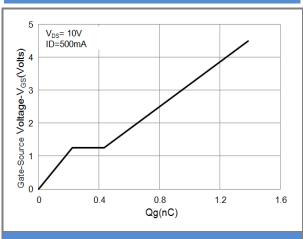








#### N-Channel TYPICAL CHARACTERISTIC CURVES



**Fig.7 Gate-Charge Characteristics** 

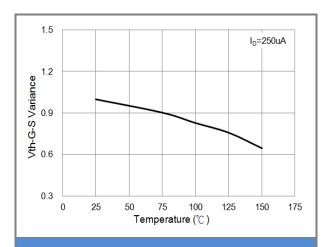


Fig.8 Threshold Voltage Variation with Temperature.

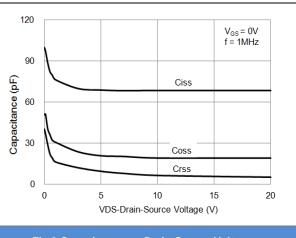


Fig.9 Capacitance vs. Drain-Source Voltage.





#### P-Channel TYPICAL CHARACTERISTIC CURVES

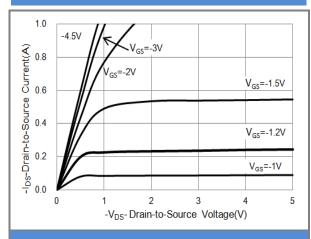
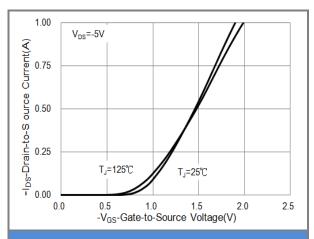


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

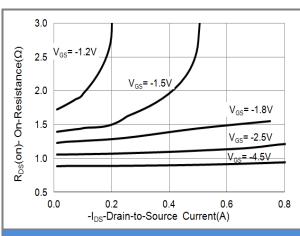


Fig.3 On-Resistance vs. Drain Current

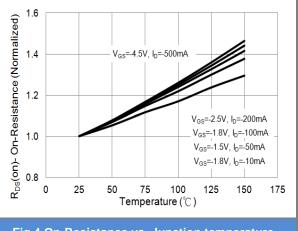
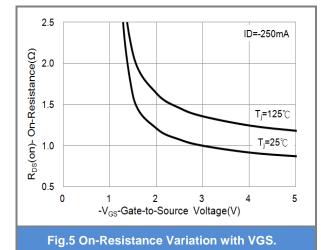
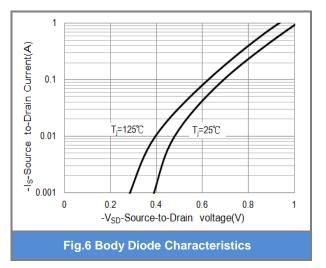


Fig.4 On-Resistance vs. Junction temperature

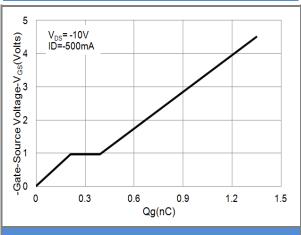








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**Fig.7 Gate-Charge Characteristics** 

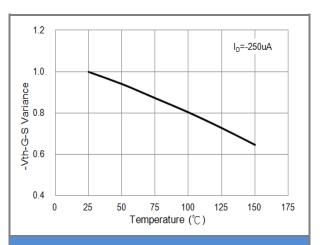


Fig.8 Threshold Voltage Variation with Temperature.

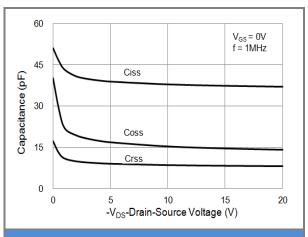


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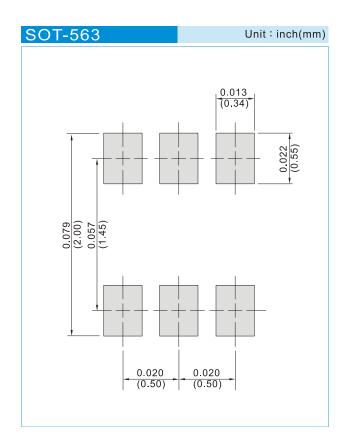




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJX8601_R1_00001	SOT-563	4K pcs / 7" reel	X61	Halogen free

#### **MOUNTING PAD LAYOUT**







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